

HIGH EFFICIENCY RECTIFIER

VOLTAGE RANGE: 700---1000 V

CURRENT: 4.0 A

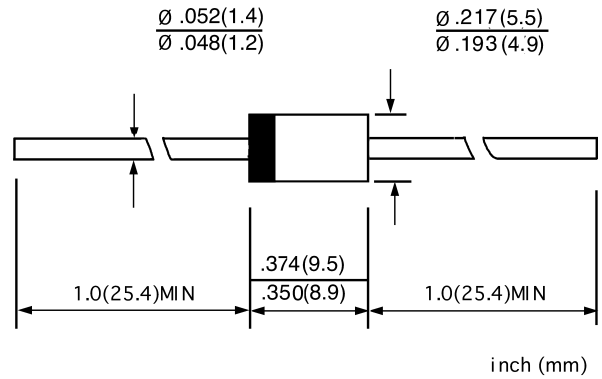
FEATURES

- ◇ Low cost
- ◇ Diffused junction
- ◇ Low leakage
- ◇ Low forward voltage drop
- ◇ High current capability
- ◇ Easily cleaned with freon, alcohol, Isopropand and similar solvents

MECHANICAL DATA

- ◇ Case: JEDEC DO-27, molded plastic
- ◇ Terminals: Axial leads, solderable per MIL-STD- 202 , Method 208
- ◇ Polarity: Color band denotes cathode
- ◇ Weight: 0.041 ounces, 1.15 grams
- ◇ Mounting: Any

DO - 27



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 50 Hz, resistive or inductive load. For capacitive load, derate by 20%.

		MUR470	MUR480	MUR490	MUR4100	UNITS
Maximum recurrent peak reverse voltage	V_{RRM}	700	800	900	1000	V
Maximum RMS voltage	V_{RMS}	490	560	630	700	V
Maximum DC blocking voltage	V_{DC}	700	800	900	1000	V
Maximum average forward rectified current 9.5mm lead length, @ $T_A=75^\circ\text{C}$	$I_{F(AV)}$	4.0				A
Peak forward surge current 10ms single half-sine-wave superimposed on rated load @ $T_J=125^\circ\text{C}$	I_{FSM}	125.0				A
Maximum instantaneous forward voltage @ 4.0A	V_F	1.8				V
Maximum reverse current @ $T_A=25^\circ\text{C}$ at rated DC blocking voltage @ $T_A=100^\circ\text{C}$	I_R	10.0 100.0				μA
Maximum reverse recovery time (Note1)	t_{rr}	75				ns
Typical junction capacitance (Note2)	C_J	50				pF
Typical thermal resistance (Note3)	$R_{\theta JA}$	30				$^\circ\text{C/W}$
Operating junction temperature range	T_J	- 55 ----- + 150				$^\circ\text{C}$
Storage temperature range	T_{STG}	- 55 ----- + 150				$^\circ\text{C}$

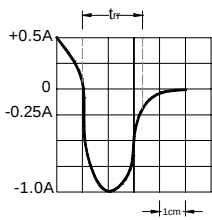
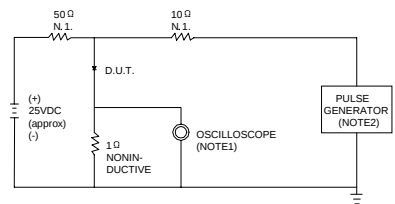
NOTE: 1. Measured with $I_F=0.5\text{A}$, $I_R=1\text{A}$, $t_r=0.25\text{A}$.

2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

3. Thermal resistance from junction to ambient.

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FIG.1 – TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC



NOTES:1.RISE TIME = 7ns MAX.INPUT IMPEDANCE =1MΩ. 22pF.
2.RISE TIME =10ns MAX.SOURCE IMPEDANCE=50 Ω.

SET TIME BASE FOR 10/20 ns/cm

FIG.2 – TYPICAL FORWARD CHARACTERISTIC

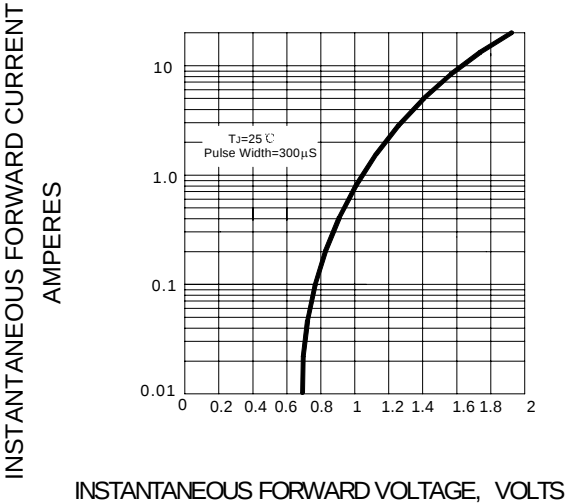


FIG.3 – FORWARD DERATING CURVE

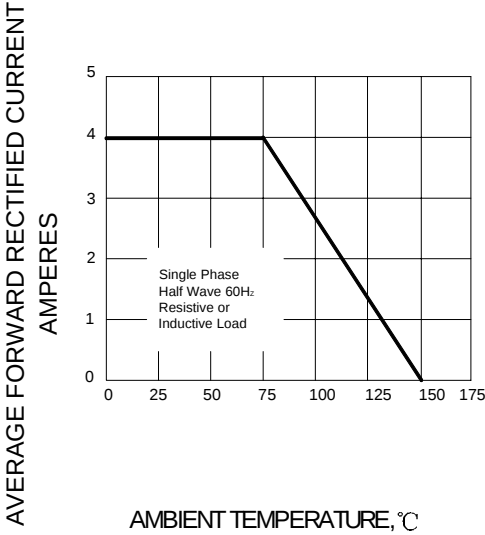


FIG.4 – PEAK FORWARD SURGE CURRENT

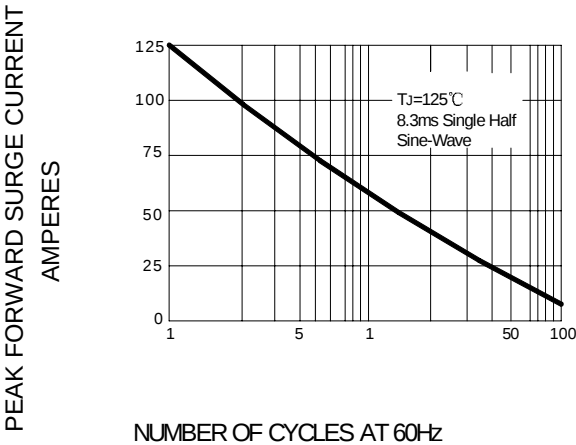


FIG.5-TYPICAL JUNCTION CAPACITANCE

